Inverter with Schmitt-Trigger Input

The MC74HC1G14 is a high speed CMOS inverter with Schmitt-Trigger input fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent LSTTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output.

The MC74HC1G14 output drive current is 1/2 compared to MC74HC series.

- High Speed: $t_{PD} = 7 \text{ns}$ (Typ) at $V_{CC} = 5 \text{V}$
- Low Power Dissipation: $I_{CC} = 1\mu A$ (Max) at $T_A = 25$ °C
- High Noise Immunity
- Balanced Propagation Delays (tpLH = tpHL)
- Output Drive Capability: 5 LSTTL
- Symmetrical Output Impedance $(I_{OH} = I_{OL} = 2mA)$
- ESD Performance: HBM > 2000V; MM > 200V

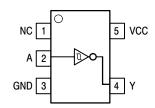


Figure 1 Pinout (Top View)



Figure 2 Logic Symbol



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MARKING DIAGRAMS



SC-88A / SOT-353/SC-70 DF SUFFIX CASE 419A



Pin 1

d = Date Code



TSOP-5/SOT-23/SC-59
DT SUFFIX
CASE 483



d = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

FUNCTION TABLE

Outputs
Н
L

MAXIMUM RATINGS*

Characteristics	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	−0.5 to +7.0	V
DC Input Voltage	V_{IN}	–0.5 to V _{CC} + 0.5	V
DC Output Voltage	V _{OUT}	–0.5 to V _{CC} + 0.5	V
Input Diode Current	I _{IK}	±20	mA
Output Diode Current (V _{OUT} < GND; V _{OUT} > V _{CC})	lok	±20	mA
DC Output Current, per Pin	l _{out}	±12.5	mA
DC Supply Current, V _{CC} and GND	lcc	±25	mA
Power dissipation in still air SC–88A† TSOP5†	P _D	200 450	mW
Lead temperature, 1 mm from case for 10 s	T _L	260	°C
Storage temperature	T _{stg}	-65 to +150	°C

^{*} Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — SC-88A Package: $-3 \text{ mW/}^{\circ}\text{C}$ from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Characteristics	Symbol	Min	Max	Unit
DC Supply Voltage	V _{CC}	2.0	6.0	V
DC Input Voltage	V _{IN}	0.0	V _{CC}	V
DC Output Voltage	V _{OUT}	0.0	V _{CC}	V
Operating Temperature Range	T _A	– 55	+125	°C
Input Rise and Fall Time $\begin{aligned} V_{CC} &= 2.0 \\ V_{CC} &= 3.0 \\ V_{CC} &= 4.5 \\ V_{CC} &= 6.0 \end{aligned}$	/ /	0 0 0 0	1000 600 500 400	ns

The θ_{JA} of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

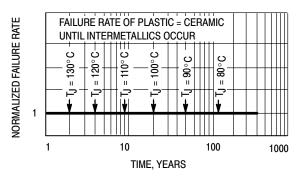


Figure 3. Failure Rate vs. Time Junction Temperature

TSOP5 Package: –6 mW/°C from 65° to 125°C

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	٦	Γ _A = 25°(3	T _A ≤	85°C	T _A ≤ 1	125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{T+}	Positive–going Input Threshold Voltage	$V_{OUT} = 0.1V$ $ I_{OUT} \le 20\mu A$	2.0 3.0 4.5 6.0	1.00 1.50 2.30 3.00	1.34 2.02 2.97 3.93	1.50 2.5 3.15 4.20	0.95 1.45 2.25 2.95	1.60 2.60 3.15 4.20	0.90 1.40 2.20 2.90	1.60 2.60 3.15 4.20	V
V _{T-}	Negative-going Input Threshold Voltage	$V_{OUT} = V_{CC} - 0.1V$ $ I_{OUT} \le 20\mu A$	2.0 3.0 4.5 6.0	0.55 1.0 1.75 2.65	0.86 1.44 2.28 3.14	1.15 1.80 2.75 3.65	0.55 1.0 1.75 2.65	1.20 1.85 2.8 3.7	0.55 1.0 1.75 2.65	1.25 1.90 2.85 3.75	V
V _H	Hysteresis Voltage	$V_{OUT} = 0.1V$ or $V_{OUT} = V_{CC} - 0.1V$ $ I_{OUT} \le 20\mu A$	2.0 3.0 4.5 6.0	0.20 0.25 0.30 0.40	0.478 0.584 0.686 0.790	0.8 0.95 1.1 1.25	0.20 0.25 0.30 0.40	0.8 0.55 1.1 1.5	0.20 0.25 0.30 0.40	0.8 0.95 1.1 1.25	V
V _{OH}	Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -20\mu\text{A}$	2.0 3.0 4.5 6.0	1.9 2.9 4.4 5.9	2.0 3.0 4.5 6.0		1.9 2.9 4.4 5.9		1.9 2.9 4.4 5.9		V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -2mA$ $I_{OH} = -2.6mA$	4.5 6.0	4.18 5.68	4.31 5.80		4.13 5.63		4.08 5.58		V
V _{OL}	Maximum Low–Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu A$	2.0 3.0 4.5 6.0		0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1		0.1 0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 2\text{mA}$ $I_{OL} = 2.6\text{mA}$	4.5 6.0		0.17 0.18	0.26 0.26		0.33 0.33		0.40 0.40	V
I _{IN}	Maximum Input Leakage Current	V _{IN} = 6.0V or GND	0 to 6.0			±0.1		±1.0		±1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	6.0			1.0		10		40	μΑ

AC ELECTRICAL CHARACTERISTICS ($C_{load} = 50 \text{ pF}$, Input $t_f = t_f = 6.0 \text{ns}$)

				7	Γ _A = 25°(;	T _A ≤	85°C	T _A ≤ 1	125°C	
Symbol	Parameter	Test Co	onditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Maximum Propogation Delay,	V _{CC} = 5.0V	C _L = 15 pF		11	21		27		35	ns
	Input A to Y	V _{CC} = 2.0V	$C_{L} = 50 \text{ pF}$		48	100		235		300	
		$V_{CC} = 3.0V$			32	45		90		135	
		$V_{CC} = 4.5V$			12	20		48		60	
		$V_{CC} = 6.0V$			9.0	17		40		50	
t _{TLH} , t _{THL}	Output Transition Time	V _{CC} = 5.0V	C _L = 15 pF		4.0	8.0		13		18	ns
		V _{CC} = 2.0V	$C_1 = 50 pF$		50	125		145		200	
		$V_{CC} = 3.0V$			22	35		45		60	
		$V_{CC} = 4.5V$			14	25		30		35	
		$V_{CC} = 6.0V$			12	21		24		31	
C _{IN}	Maximum Input Capacitance				5	10		10		10	pF

		Typical @ 25°C, V _{CC} = 5.0V		1
C _{PD}	Power Dissipation Capacitance (Note 1.)	10	pF	

^{1.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

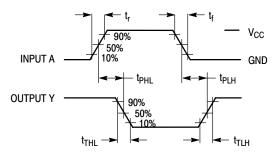
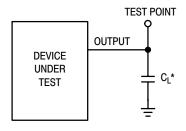


Figure 4. Switching Waveforms



* Includes all probe and jig capacitance

Figure 5. Test Circuit

DEVICE ORDERING INFORMATION

	Device Nomenclature							
Device Order Number	Circuit Indicator	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type (Name/SOT#/ Common Name)	Tape and Reel Size
MC74HC1G14DFT2	MC	74	HC1G	14	DF	T2	SC-88A / SOT-353 / SC-70	178 mm (7") 3000 Unit
MC74HC1G14DFT4	MC	74	HC1G	14	DF	T4	SC-88A / SOT-353 / SC-70	330 mm (13") 10000 Unit
MC74HC1G14DTT1	МС	74	HC1G	14	DT	T1	TSOPS / SOT-23 / SC-59	178 mm (7") 3000 Unit
MC74HC1G14DTT3	MC	74	HC1G	14	DT	Т3	TSOPS / SOT-23 / SC-59	330 mm (13") 10000 Unit

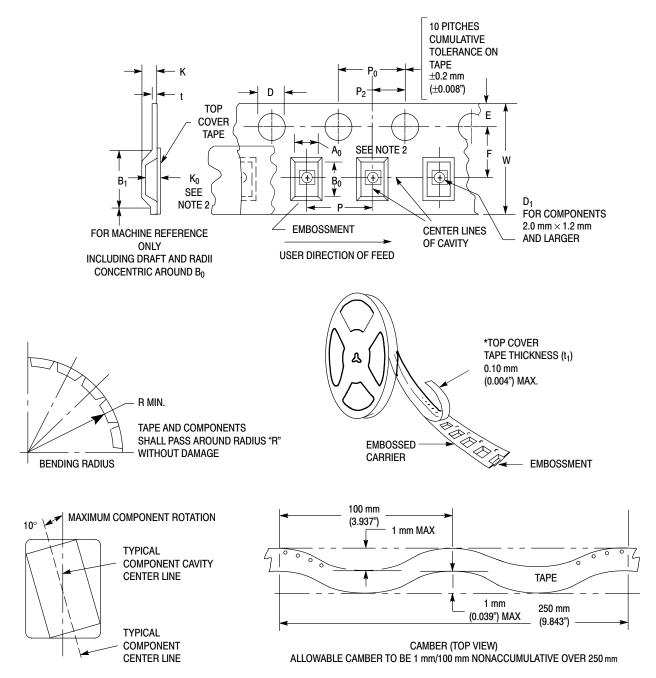


Figure 6. Carrier Tape Specifications

EMBOSSED CARRIER DIMENSIONS (See Notes 1 and 2)

Tape Size	B ₁ Max	D	D ₁	E	F	К	Р	P ₀	P ₂	R	Т	w
8 mm	4.35 mm (0.171")	1.5 +0.1/ -0.0 mm (0.059 +0.004/ -0.0")	1.0 mm Min (0.039")	1.75 ±0.1 mm (0.069 ±0.004")	3.5 ±0.5 mm (1.38 ±0.002")	2.4 mm (0.094")	4.0 ±0.10 mm (0.157 ±0.004")	4.0 ±0.1 mm (0.156 ±0.004")	2.0 ±0.1 mm (0.079 ±0.002")	25 mm (0.98")	0.3 ±0.05 mm (0.01 +0.0038/ -0.0002")	8.0 ±0.3 mm (0.315 ±0.012")

^{1.} Metric Dimensions Govern-English are in parentheses for reference only.

^{2.} A₀, B₀, and K₀ are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

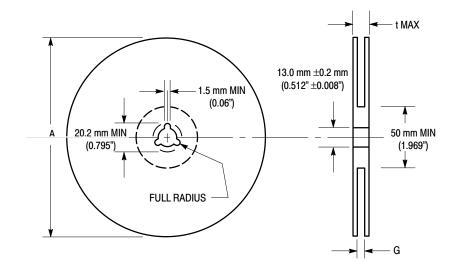


Figure 7. Reel Dimensions

REEL DIMENSIONS

Tape Size	T&R Suffix	A Max	G	t Max
8 mm	T1, T2	178 mm (7")	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56")
8 mm	T3, T4	330 mm (13")	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56")

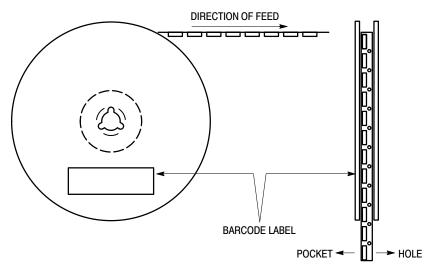


Figure 8. Reel Winding Direction

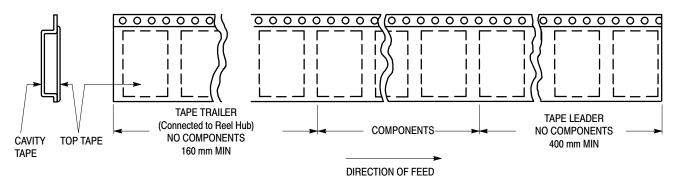


Figure 9. Tape Ends for Finished Goods

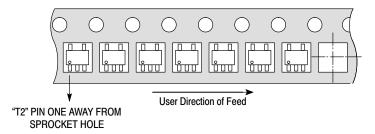


Figure 10. DFT2 and DFT4 (SC88A) Reel Configuration/Orientation

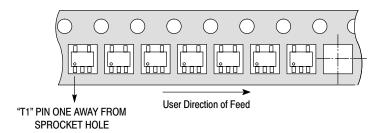
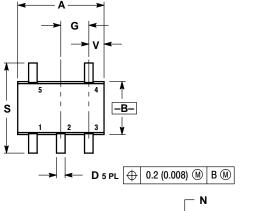


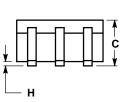
Figure 11. DTT1 and DTT3 (TSOP5) Reel Configuration/Orientation

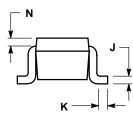
PACKAGE DIMENSIONS

SC-88A / SOT-353 / SC-70 **DF SUFFIX**

5-LEAD PACKAGE CASE 419A-01 ISSUE B

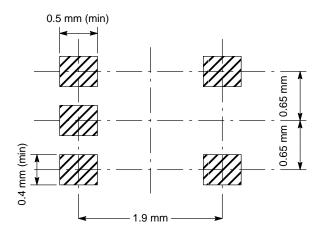






- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MM.

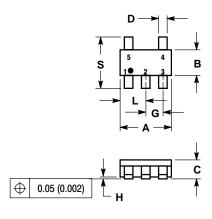
	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
C	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008 REF		0.20	REF	
S	0.079	0.087	2.00	2.20	
٧	0.012	0.016	0.30	0.40	

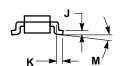


PACKAGE DIMENSIONS

TSOP-5/SOT-23/SC-59 **DT SUFFIX**

5-LEAD PACKAGE CASE 483-01 ISSUE A





NOTES:

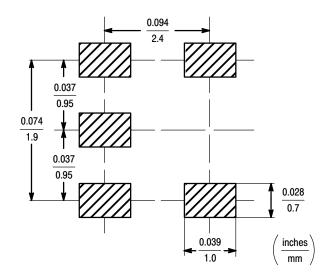
- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.1142	0.1220
В	1.30	1.70	0.0512	0.0669
С	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.00	0.0335	0.0413
Н	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
M	0 °	10°	0°	10°
S	2.50	3.00	0.0985	0.1181



Notes



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